

MiniSKiiP<sup>®</sup> 1

3-phase bridge rectifier + brake chopper + 3-phase bridge inverter SKIIP 12NAB126V1

#### **Features**

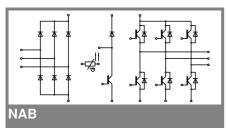
- Fast Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

### **Typical Applications\***

- Inverter up to 10 kVA
- Typical motor power 5,5 kW

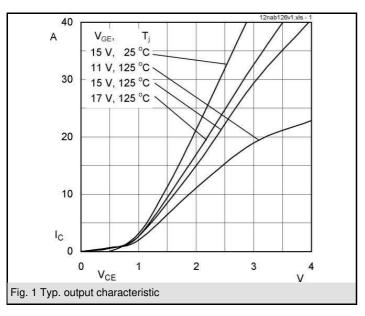
#### **Remarks**

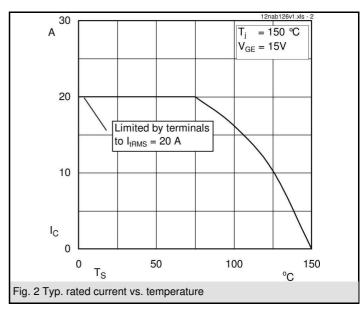
• V<sub>CEsat</sub> , V<sub>F</sub> = chip level value

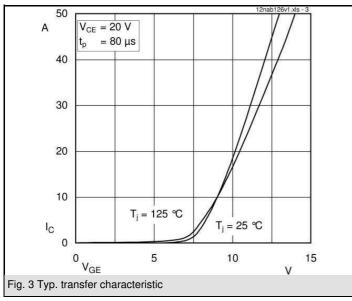


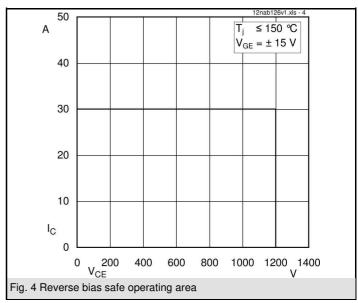
<b>Absolute Maximum Ratings</b> $T_s = 25  ^{\circ}\text{C}$ , unless otherwise specified								
Symbol	Conditions	Values	Units					
IGBT - Inverter, Chopper								
$V_{CES}$		1200	V					
I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	28 (22)	Α					
I <sub>CRM</sub>		30	Α					
$V_{GES}$		± 20	V					
T <sub>j</sub>		- 40 <b>+</b> 150	°C					
Diode - Inverter, Chopper								
I <sub>F</sub>	$T_s = 25 (70) ^{\circ}C$	26 (20)	Α					
I <sub>FRM</sub>		30	Α					
$T_j$		- 40 <b>+</b> 150	°C					
Diode - Rectifier								
$V_{RRM}$		1600	V					
I <sub>F</sub>	T <sub>s</sub> = 70 °C	35	Α					
I <sub>FSM</sub>	$t_{\rm p}$ = 10 ms, sin 180 °, $T_{\rm i}$ = 25 °C	220	Α					
i²t	$t_{\rm D}^{\rm r}$ = 10 ms, sin 180 °, $T_{\rm i}$ = 25 °C	240	A²s					
T <sub>j</sub>		- 40 <b>+</b> 150	°C					
Module	•		•					
I <sub>tRMS</sub>	per power terminal (20 A / spring)	20	Α					
T <sub>stg</sub>		- 40 <b>+</b> 125	°C					
V <sub>isol</sub>	AC, 1 min.	2500	V					

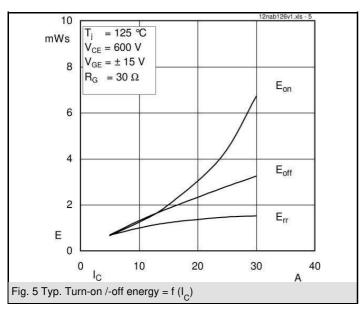
Characteristics		$T_s = 25$ °C, unless otherwise specified							
Symbol	Conditions	min.	typ.	max.	Units				
IGBT - Inverter, Chopper									
$V_{CEsat}$ $V_{GE(th)}$ $V_{CE(TO)}$	$I_{Cnom} = 15 \text{ A}, T_j = 25 (125) ^{\circ}\text{C}$ $V_{GE} = V_{CE}, I_C = 0,6 \text{ mA}$ $T_i = 25 (125) ^{\circ}\text{C}$	5	1,7 (2) 5,8 1 (0,9)	2,1 (2,4) 6,5 1,2 (1,1)	V V				
r <sub>T</sub> C <sub>ies</sub>	T <sub>j</sub> = 25 (125) °C V <sub>CE</sub> = 25 V, V <sub>GE</sub> = 0 V, f = 1 MHz		47 (73) 1	60 (87)	mΩ nF				
C <sub>oes</sub> C <sub>res</sub>	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ per IGBT		0,1 0,1 1,15		nF nF K/W				
$\begin{aligned} R_{th(j-s)} \\ t_{d(on)} \\ t_{r} \\ t_{d(off)} \\ t_{f} \\ E_{on} \\ E_{off} \end{aligned}$	under following conditions $V_{CC} = 600 \text{ V}, V_{GE} = \pm 15 \text{ V}$ $I_{Cnom} = 15 \text{ A}, T_j = 125^{\circ}\text{C}$ $R_{Gon} = R_{Goff} = 30 \Omega$ inductive load		25 25 385 90 2 1,9		ns ns ns ns ms mJ				
$V_F = V_{EC}$ $V_{(TO)}$ $r_T$	I <sub>Fnom</sub> = 15 A, T <sub>j</sub> = 25 (125) °C   T <sub>j</sub> = 25 (125) °C   T <sub>j</sub> = 25 (125) °C   per diode		1,6 (1,6) 1 (0,8) 40 (53) 1,95	, ,	V V mΩ K/W				
$\begin{aligned} &R_{th(j-s)} \\ &I_{RRM} \\ &Q_{rr} \\ &E_{rr} \end{aligned}$	under following conditions $I_{Fnom} = 15 \text{ A}, V_R = 600 \text{ V}$ $V_{GE} = 0 \text{ V}, T_j = 125 ^{\circ}\text{C}$ $di_F/dt = 900 \text{ A/µs}$		25 3 1,3		Α μC mJ				
Diode - R	ectifier								
$V_{F} \\ V_{(TO)} \\ r_{T} \\ R_{th(j-s)}$	$ \begin{aligned} &   I_{\text{Fnom}} = 15 \text{ A, T}_j = 25 \text{ °C} \\ &   T_j = 150 \text{ °C} \\ &   T_j = 150 \text{ °C} \\ &   \text{per diode} \end{aligned} $		1,1 0,8 20 1,5		V V mΩ K/W				
	ture Sensor	•			-				
R <sub>ts</sub>	3 %, T <sub>r</sub> = 25 (100) °C	1000(1670)		Ω					
Mechanic	cal Data				•				
w M <sub>s</sub>	Mounting torque	2	35	2,5	g Nm				

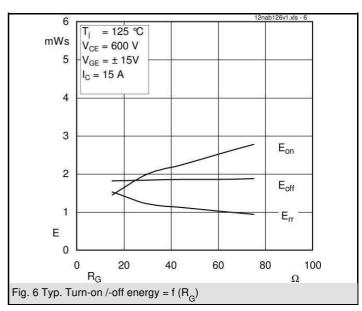


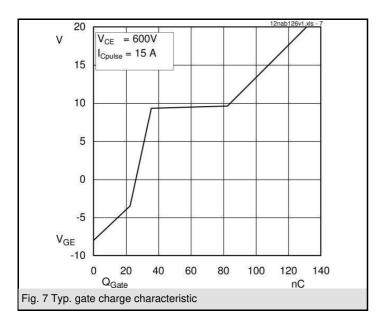


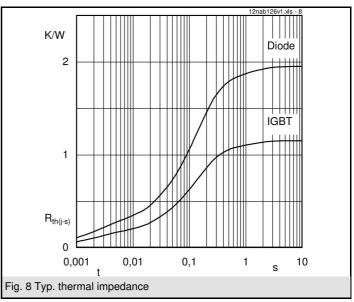


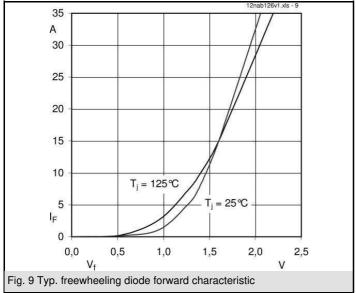


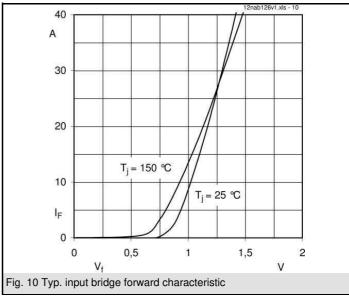


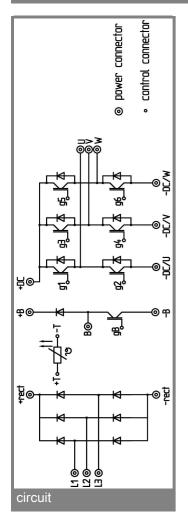


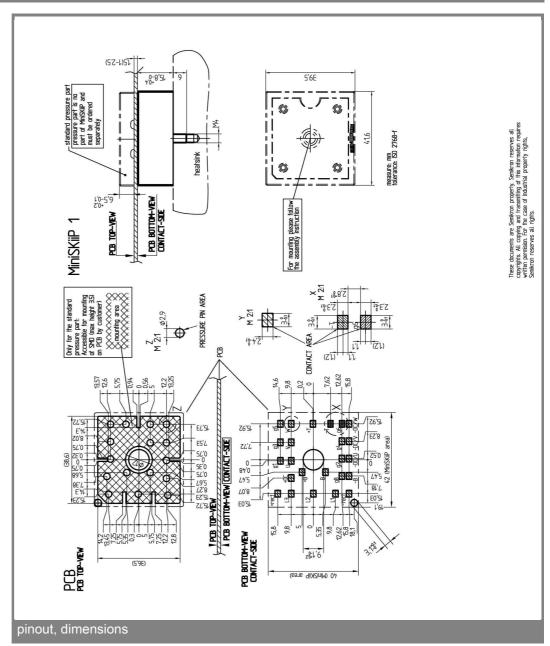












This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

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<sup>\*</sup> The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.